LM148,LM248,LM348

LM148/LM248/LM348 Quad 741 Op Amps

Datasheet.Directory



Literature Number: SNOSBT2D



LM148/LM248/LM348 Quad 741 Op Amps

General Description

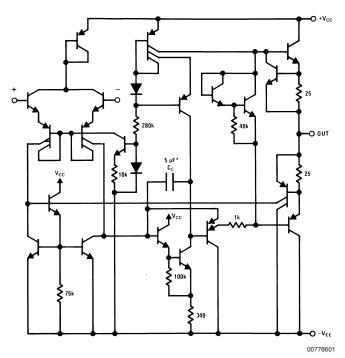
The LM148 series is a true quad 741. It consists of four independent, high gain, internally compensated, low power operational amplifiers which have been designed to provide functional characteristics identical to those of the familiar 741 operational amplifier. In addition the total supply current for all four amplifiers is comparable to the supply current of a single 741 type op amp. Other features include input offset currents and input bias current which are much less than those of a standard 741. Also, excellent isolation between amplifiers has been achieved by independently biasing each amplifier and using layout techniques which minimize thermal coupling.

The LM148 can be used anywhere multiple 741 or 1558 type amplifiers are being used and in applications where amplifier matching or high packing density is required. For lower power refer to LF444.

Features

- 741 op amp operating characteristics
- Class AB output stage—no crossover distortion
- Pin compatible with the LM124
- Overload protection for inputs and outputs
- Low supply current drain: 0.6 mA/Amplifier
- Low input offset voltage: 1 mV
- Low input offset current: 4 nA
- Low input bias current 30 nA
- High degree of isolation between amplifiers: 120 dB
- Gain bandwidth product
- LM148 (unity gain): 1.0 MHz

Schematic Diagram



* 1 pF in the LM149

Absolute Maximum Ratings (Note 4)

Distributors for availability and specifications.

500V

500V

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/

	LM148	LM248	LM348
Supply Voltage	±22V	±18V	±18V
Differential Input Voltage	±44V	±36V	±36V
Output Short Circuit Duration (Note 1)	Continuous	Continuous	Continuous
Power Dissipation (P _d at 25°C) and			
Thermal Resistance (θ_{jA}) , (Note 2)			
Molded DIP (N) P _d	_	_	750 mW
$ heta_{jA}$	_	_	100°C/W
Cavity DIP (J) P _d	1100 mW	800 mW	700 mW
$ heta_{\sf JA}$	110°C/W	110°C/W	110°C/W
Maximum Junction Temperature (T _{jMAX})	150°C	110°C	100°C
Operating Temperature Range	$-55^{\circ}C \le T_A \le +125^{\circ}C$	$-25^{\circ}C \le T_A \le +85^{\circ}C$	$0^{\circ}C \leq T_{A} \leq +70^{\circ}C$
Storage Temperature Range	-65°C to +150°C	-65°C to +150°C	-65°C to +150°C
Lead Temperature (Soldering, 10 sec.) Ceramic	300°C	300°C	300°C
Lead Temperature (Soldering, 10 sec.) Plastic			260°C
Soldering Information			
Dual-In-Line Package			
Soldering (10 seconds)	260°C	260°C	260°C
Small Outline Package			
Vapor Phase (60 seconds)	215°C	215°C	215°C
Infrared (15 seconds)	220°C	220°C	220°C
See AN-450 "Surface Mounting Methods and Their E	Effect on Product Reliability	" for other methods of s	oldering surface
mount			
devices.			

500V

Electrical Characteristics

ESD tolerance (Note 5)

(Note 3)

Parameter	Conditions	LM148			LM248			LM348			Units
		Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	
Input Offset Voltage	$T_A = 25^{\circ}C, R_S \le 10 \text{ k}\Omega$		1.0	5.0		1.0	6.0		1.0	6.0	mV
Input Offset Current	T _A = 25°C		4	25		4	50		4	50	nA
Input Bias Current	T _A = 25°C		30	100		30	200		30	200	nA
Input Resistance	T _A = 25°C	0.8	2.5		0.8	2.5		0.8	2.5		MΩ
Supply Current All Amplifiers	$T_A = 25^{\circ}C, V_S = \pm 15V$		2.4	3.6		2.4	4.5		2.4	4.5	mA
Large Signal Voltage Gain	$T_A = 25^{\circ}C, V_S = \pm 15V$	50	160		25	160		25	160		V/mV
	$V_{OUT} = \pm 10V, R_L \ge 2 k\Omega$										
Amplifier to Amplifier	$T_A = 25$ °C, $f = 1$ Hz to 20 kHz										
Coupling	(Input Referred) See Crosstalk		-120			-120			-120		dB
	Test Circuit										
Small Signal Bandwidth	T _A = 25°C,		1.0			1.0			1.0		MHz
	LM148 Series										
Phase Margin	$T_A = 25^{\circ}C$,		60			60			60		degrees
	LM148 Series (A _V = 1)										
Slew Rate	$T_A = 25^{\circ}C$,		0.5			0.5			0.5		V/µs
	LM148 Series (A _V = 1)										
Output Short Circuit Current	$T_A = 25^{\circ}C$		25			25			25		mA
Input Offset Voltage	$R_S \le 10 \text{ k}\Omega$			6.0			7.5			7.5	mV
Input Offset Current				75			125			100	nA

Electrical Characteristics (Continued)

(Note 3)

Parameter	Conditions	LM148		LM248			LM348			Units	
		Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	
Input Bias Current				325			500			400	nA
Large Signal Voltage Gain	$V_S = \pm 15V, V_{OUT} = \pm 10V,$	25			15			15			V/mV
	$R_L > 2 k\Omega$										
Output Voltage Swing	$V_S = \pm 15V$, $R_L = 10 \text{ k}\Omega$	±12	±13		±12	±13		±12	±13		V
	$R_L = 2 k\Omega$	±10	±12		±10	±12		±10	±12		V
Input Voltage Range	V _S = ±15V	±12			±12			±12			V
Common-Mode Rejection	$R_S \le 10 \text{ k}\Omega$	70	90		70	90		70	90		dB
Ratio											
Supply Voltage Rejection	$R_S \le 10 \text{ k}\Omega, \ \pm 5V \le V_S \le \pm 15V$	77	96		77	96		77	96		dB

Note 1: Any of the amplifier outputs can be shorted to ground indefinitely; however, more than one should not be simultaneously shorted as the maximum junction temperature will be exceeded.

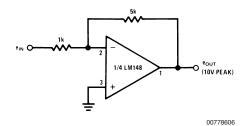
Note 2: The maximum power dissipation for these devices must be derated at elevated temperatures and is dicated by T_{JMAX} , θ_{JA} , and the ambient temperature, T_A . The maximum available power dissipation at any temperature is $P_d = (T_{JMAX} - T_A)/\theta_{JA}$ or the 25°C P_{DMAX} , whichever is less.

Note 3: These specifications apply for $V_S = \pm 15V$ and over the absolute maximum operating temperature range $(T_L \le T_A \le T_H)$ unless otherwise noted.

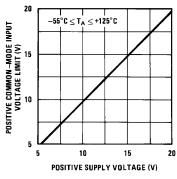
Note 4: Refer to RETS 148X for LM148 military specifications.

Note 5: Human body model, 1.5 k Ω in series with 100 pF.

Cross Talk Test Circuit $V_s = \pm 15V$

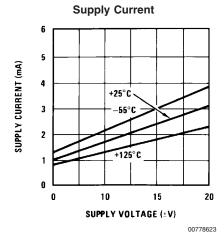


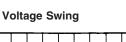
CHANNEL UNDER TEST (7, 8, 14) 00778607

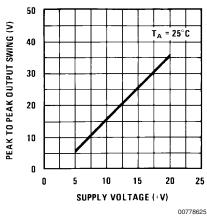


00778643

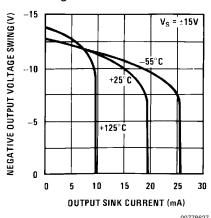
Typical Performance Characteristics



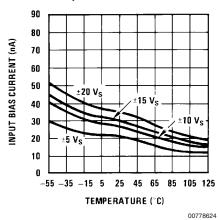




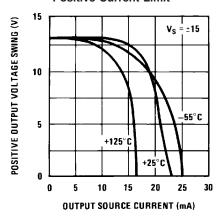
Negative Current Limit



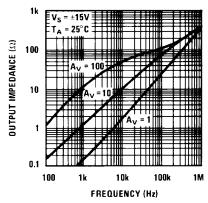
Input Bias Current



Positive Current Limit



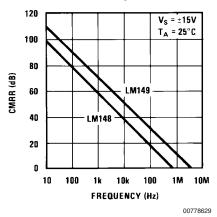
Output Impedance



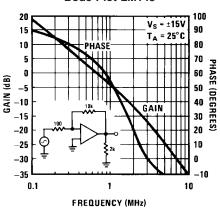
00778628

Typical Performance Characteristics (Continued)

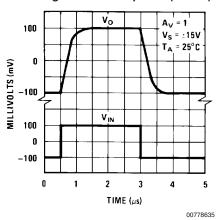
Common-Mode Rejection Ratio



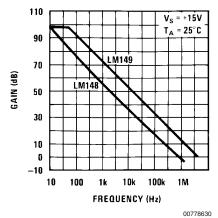
Bode Plot LM148



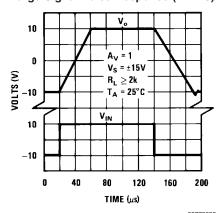
Small Signal Pulse Response (LM148)



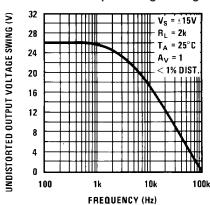
Open Loop Frequency Response



Large Signal Pulse Response (LM148)

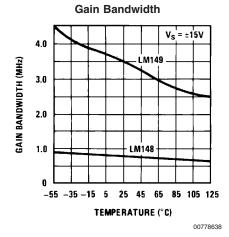


Undistorted Output Voltage Swing

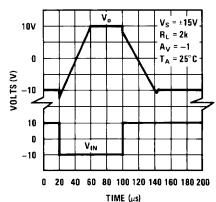


00778637

Typical Performance Characteristics (Continued)

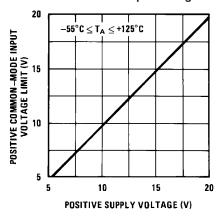


Inverting Large Signal Pulse Response (LM148)

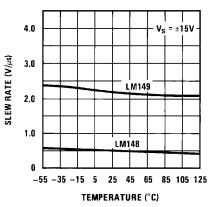


Positive Common-Mode Input Voltage Limit

00778641

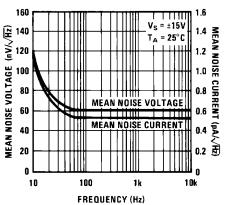


Slew Rate



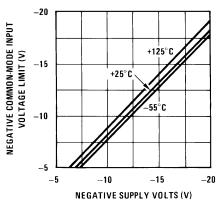
00770039

Input Noise Voltage and Noise Current



00778642

Negative Common-Mode Input Voltage Limit



00778605

Application Hints

The LM148 series are quad low power 741 op amps. In the proliferation of quad op amps, these are the first to offer the convenience of familiar, easy to use operating characteristics of the 741 op amp. In those applications where 741 op amps have been employed, the LM148 series op amps can be employed directly with no change in circuit performance.

The package pin-outs are such that the inverting input of each amplifier is adjacent to its output. In addition, the amplifier outputs are located in the corners of the package which simplifies PC board layout and minimizes package related capacitive coupling between amplifiers.

The input characteristics of these amplifiers allow differential input voltages which can exceed the supply voltages. In addition, if either of the input voltages is within the operating common-mode range, the phase of the output remains correct. If the negative limit of the operating common-mode range is exceeded at both inputs, the output voltage will be positive. For input voltages which greatly exceed the maximum supply voltages, either differentially or common-mode, resistors should be placed in series with the inputs to limit the current.

Like the LM741, these amplifiers can easily drive a 100 pF capacitive load throughout the entire dynamic output voltage and current range. However, if very large capacitive loads must be driven by a non-inverting unity gain amplifier, a resistor should be placed between the output (and feedback connection) and the capacitance to reduce the phase shift resulting from the capacitive loading.

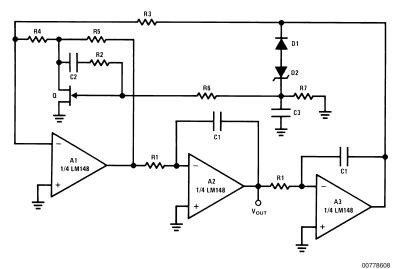
The output current of each amplifier in the package is limited. Short circuits from an output to either ground or the power supplies will not destroy the unit. However, if multiple output shorts occur simultaneously, the time duration should be short to prevent the unit from being destroyed as a result of excessive power dissipation in the IC chip.

As with most amplifiers, care should be taken lead dress, component placement and supply decoupling in order to ensure stability. For example, resistors from the output to an input should be placed with the body close to the input to minimize "pickup" and maximize the frequency of the feedback pole which capacitance from the input to ground creates.

A feedback pole is created when the feedback around any amplifier is resistive. The parallel resistance and capacitance from the input of the device (usually the inverting input) to AC ground set the frequency of the pole. In many instances the frequency of this pole is much greater than the expected 3 dB frequency of the closed loop gain and consequently there is negligible effect on stability margin. However, if the feedback pole is less than approximately six times the expected 3 dB frequency a lead capacitor should be placed from the output to the input of the op amp. The value of the added capacitor should be such that the RC time constant of this capacitor and the resistance it parallels is greater than or equal to the original feedback pole time constant.

Typical Applications—LM148

One Decade Low Distortion Sinewave Generator



$$f = \frac{1}{2\pi R1C1} \times \sqrt{K}, \, K = \frac{R4R5}{R3} \left(\frac{1}{r_{DS}} + \frac{1}{R4} + \frac{1}{R5}\right), \quad r_{DS} \approx \frac{R_{ON}}{\left(1 - \frac{V_{GS}}{V_P}\right)^{1/2}}$$

 f_{MAX} = 5 kHz, THD \leq 0.03%

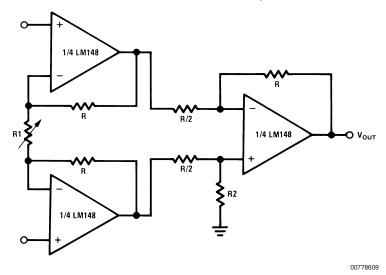
R1 = 100k pot. C1 = 0.0047 $\mu F,~C2$ = 0.01 $\mu F,~C3$ = 0.1 $\mu F,~R2$ = R6 = R7 = 1M,

R3 = 5.1k, $R4 = 12\Omega$, $R5 = 240\Omega$, Q = NS5102, D1 = 1N914, D2 = 3.6V avalanche

diode (ex. LM103), $V_S = \pm 15V$

A simpler version with some distortion degradation at high frequencies can be made by using A1 as a simple inverting amplifier, and by putting back to back zeners in the feedback loop of A3.

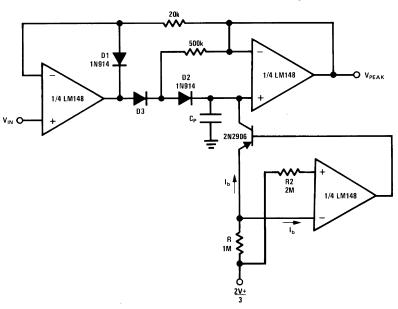
Low Cost Instrumentation Amplifier



 $V_{OUT} = 2 \bigg(\frac{2R}{R1} + 1 \bigg) \text{ , } V_{\overline{S}} - 3V \leq V_{IN\,CM} \leq {V_S}^+ - 3V,$

 $V_S = \pm 15V$ R = R2, trim R2 to boost CMRR

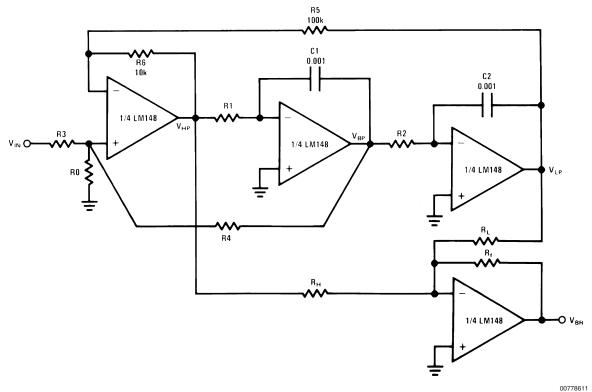
Low Drift Peak Detector with Bias Current Compensation



00778610

Adjust R for minimum drift D3 low leakage diode D1 added to improve speed $V_S = \pm 15V$

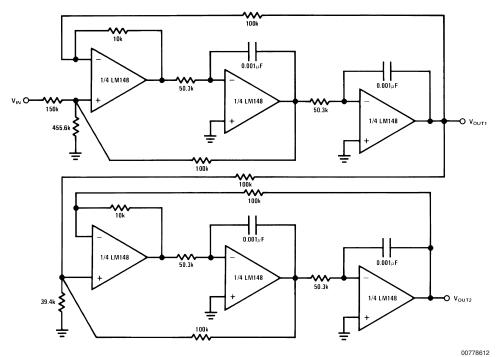
Universal State-Variable Filter



Tune Q through R0, For predictable results: f_Q Q \leq 4 x 10^4 Use Band Pass output to tune for Q

$$\begin{split} \frac{V_{(s)}}{V_{IN(s)}} &= \frac{N_{(s)}}{D_{(s)}}, \ D(s) = S^2 + \frac{S\omega_0}{Q} + \omega_0^2 \\ N_{HP(s)} &= S^2 \, H_{OHP}, \ N_{BP(s)} = \frac{-s\omega_0 \, H_{OBP}}{Q} \quad N_{LP} = \omega_0^2 \, H_{OLP}, \\ f_0 &= \frac{1}{2\pi} \, \sqrt{\frac{R6}{R5}} \, \sqrt{\frac{1}{t1t2}}, \ t_i = R_i C_i \, , \ Q = \left(\frac{1 \, + \, R4 |R3 \, + \, R4 |R0}{1 \, + \, R6 |R5}\right) \left(\frac{R6}{R5} \frac{t_1}{t_2}\right)^{1/2} \\ f_{NOTCH} &= \frac{1}{2\pi} \left(\frac{R_H}{R_L \, t_1 \, t_2}\right)^{1/2}, \ H_{OHP} = \frac{1 \, + \, R6 |R5}{1 \, + \, R3 |R0 \, + \, R3 |R4}, H_{OBP} = \frac{1 \, + \, R4 |R3 \, + \, R4 |R0}{1 \, + \, R3 |R0 \, + \, R3 |R4} \\ H_{OLP} &= \frac{1 \, + \, R5 |R6}{1 \, + \, R3 |R0 \, + \, R3 |R4} \end{split}$$

A 1 kHz 4 Pole Butterworth

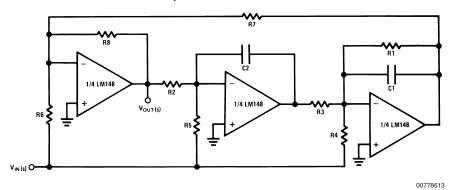


Use general equations, and tune each section separately

 $Q_{1stSECTION} = 0.541, \ Q_{2ndSECTION} = 1.306$

The response should have 0 dB peaking

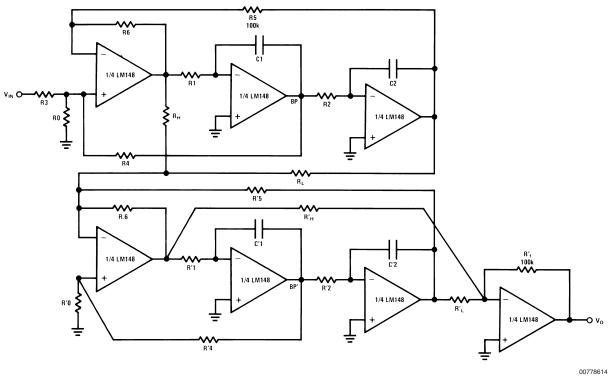
A 3 Amplifier Bi-Quad Notch Filter



$$\label{eq:Q} \begin{aligned} Q &= \sqrt{\frac{R8}{R7}} \times \frac{R1C1}{\sqrt{R3C2R2C1}}, \ \ f_0 &= \frac{1}{2\pi} \sqrt{\frac{R8}{R7}} \times \frac{1}{\sqrt{R2R3C1C2}}, \ \ f_{NOTCH} &= \frac{1}{2\pi} \sqrt{\frac{R6}{R3R5R7C1C2}} \\ \text{Necessary condition for notch:} \ \frac{1}{R6} &= \frac{R1}{R4R7} \end{aligned}$$

Ex: $f_{NOTCH} = 3$ kHz, Q = 5, R1 = 270k, R2 = R3 = 20k, R4 = 27k, R5 = 20k, R6 = R8 = 10k, R7 = 100k, C1 = C2 = 0.001 µF Better noise performance than the state-space approach.

A 4th Order 1 kHz Elliptic Filter (4 Poles, 4 Zeros)



R1C1 = R2C2 = t

R'1C'1 = R'2C'2 = t'

 $f_{C} = 1 \text{ kHz}, \ f_{S} = 2 \text{ kHz}, \ f_{p} = 0.543, \ f_{Z} = 2.14, \ Q = 0.841, \ f'_{P} = 0.987, \ f'_{Z} = 4.92, \ Q' = 4.403, \ \text{normalized to ripple BW}$

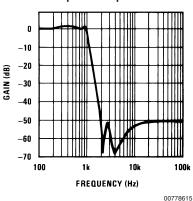
$$f = \frac{1}{2\pi R1C1} \times \sqrt{K}, \, K = \frac{R4R5}{R3} \left(\frac{1}{r_{DS}} + \frac{1}{R4} + \frac{1}{R5} \right), \quad r_{DS} \approx \frac{R_{ON}}{\left(1 - \frac{V_{GS}}{V_{P}} \right)^{1\!/\!2}}$$

Use the BP outputs to tune Q, Q', tune the 2 sections separately

 $R1 = R2 = 92.6k, R3 = R4 = R5 = 100k, R6 = 10k, R0 = 107.8k, R_L = 100k, R_H = 155.1k,$

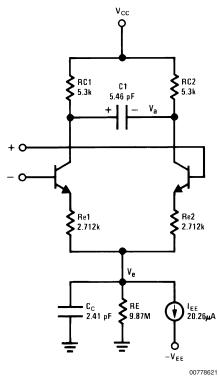
 $R'1 = R'2 = 50.9k, \; R'4 = R'5 = 100k, \; R'6 = 10k, \; R'0 = 5.78k, \; R'_L = 100k, \; R'_H = 248.12k, \; R'f = 100k. \; All \; capacitors \; are \; 0.001 \; \mu F. \; All \; capacitors \; are \; 0.001 \; \mu F. \; All \; capacitors \; are \; 0.001 \; \mu F. \; All \; capacitors \; are \; 0.001 \; \mu F. \; All \; capacitors \; are \; 0.001 \; \mu F. \; All \; capacitors \; are \; 0.001 \; \mu F. \; All \; capacitors \; are \; 0.001 \; \mu F. \; All \; capacitors \; are \; 0.001 \; \mu F. \; All \; capacitors \; are \; 0.001 \; \mu F. \; All \; capacitors \; are \; 0.001 \; \mu F. \; All \; capacitors \; are \; 0.001 \; \mu F. \; All \; capacitors \; are \; 0.001 \; \mu F. \; All \; capacitors \; are \; 0.001 \; \mu F. \; All \; capacitors \; are \; 0.001 \; \mu F. \; All \; capacitors \; are \; 0.001 \; \mu F. \; All \; capacitors \; are \; 0.001 \; \mu F. \; All \; capacitors \; are \; 0.001 \; \mu F. \; All \; capacitors \; are \; 0.001 \; \mu F. \; All \; capacitors \; are \; 0.001 \; \mu F. \; All \; capacitors \; are \; 0.001 \; a$

Lowpass Response



Typical Simulation

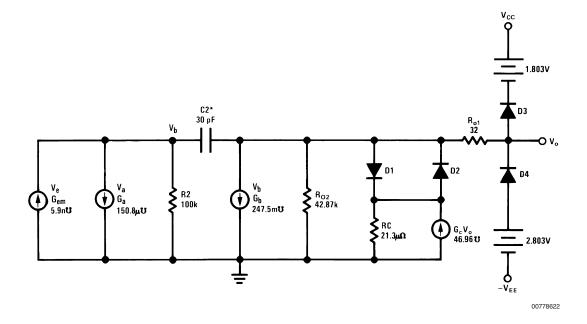
LM148, LM741 Macromodel for Computer Simulation



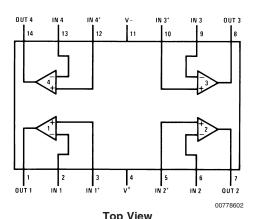
For more details, see IEEE Journal of Solid-State Circuits, Vol. SC-9, No. 6, December 1974

Note 6: $_{01} = 112I_{S} = 8 \times 10^{-16}$

Note 7: $_{02} = 144 ^{*}C2 = 6 \text{ pF for LM} 149$

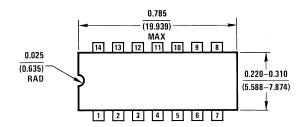


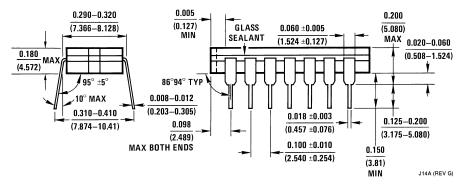
Connection Diagram



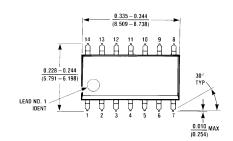
Top View
Order Number LM148J, LM148J/883, LM248J, LM348M, or LM348N
See NS Package Number J14A, M14A or N14A
LM148J is available per JM38510/11001

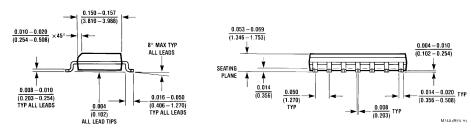
Physical Dimensions inches (millimeters) unless otherwise noted





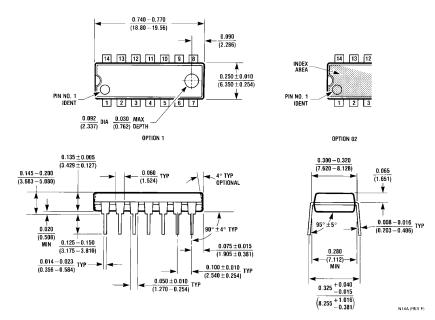
Ceramic Dual-In-Line Package (J) Order Number LM148J, LM148J/883, LM248J **NS Package Number J14A**





S.O. Package (M) Order Number LM348M or LM348MX NS Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



Molded Dual-In-Line Package (N) Order Number LM348N NS Package Number N14A

LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT AND GENERAL COUNSEL OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
- A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

BANNED SUBSTANCE COMPLIANCE

National Semiconductor certifies that the products and packing materials meet the provisions of the Customer Products Stewardship Specification (CSP-9-111C2) and the Banned Substances and Materials of Interest Specification (CSP-9-111S2) and contain no "Banned Substances" as defined in CSP-9-111S2.



National Semiconductor Americas Customer Support Center

Email: new.feedback@nsc.com Tel: 1-800-272-9959

www.national.com

National Semiconductor Europe Customer Support Center Fax: +49 (0) 180-530 85 86

Email: europe.support@nsc.com
Deutsch Tel: +49 (0) 69 9508 6208
English Tel: +44 (0) 870 24 0 2171
Français Tel: +33 (0) 1 41 91 8790

National Semiconductor
Asia Pacific Customer
Support Center
Email: ap.support@nsc.com

National Semiconductor Japan Customer Support Center Fax: 81-3-5639-7507 Email: jpn.feedback@nsc.com Tel: 81-3-5639-7560

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Applications

Audio www.ti.com/audio Communications and Telecom www.ti.com/communications **Amplifiers** amplifier.ti.com Computers and Peripherals www.ti.com/computers dataconverter.ti.com Consumer Electronics www.ti.com/consumer-apps **Data Converters DLP® Products** www.dlp.com **Energy and Lighting** www.ti.com/energy DSP dsp.ti.com Industrial www.ti.com/industrial Clocks and Timers www.ti.com/clocks Medical www.ti.com/medical Interface interface.ti.com Security www.ti.com/security

Logic logic.ti.com Space, Avionics and Defense www.ti.com/space-avionics-defense

Power Mgmt power.ti.com Transportation and Automotive www.ti.com/automotive
Microcontrollers microcontroller.ti.com Video and Imaging www.ti.com/video

RFID <u>www.ti-rfid.com</u>
OMAP Mobile Processors www.ti.com/omap

Wireless Connectivity www.ti.com/wirelessconnectivity

TI E2E Community Home Page e2e.ti.com

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2011, Texas Instruments Incorporated